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1N4942

THRU

1N4948

Features

- Low Leakage Current
- Metalurgically Bonded Construction
- Low Cost
- Fast Switching For High Efficiency

Maximum Ratings

- Operating Temperature: -55°C to +125°C
- Storage Temperature: -55°C to +150°C
- Maximum Thermal Resistance; 50°C/W Junction To Ambient

Catalog Number	Device Marking	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
1N4942	---	200V	140V	200V
1N4944	---	400V	280V	400V
1N4946	---	600V	420V	600V
1N4947	---	800V	560V	800V
1N4948	---	1000V	700V	1000V

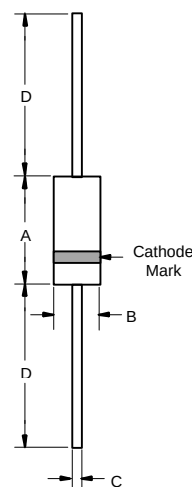
Electrical Characteristics @ 25°C Unless Otherwise Specified

Average Forward Current	$I_{F(AV)}$	1.0A	$T_A = 55^\circ\text{C}$
Peak Forward Surge Current	I_{FSM}	25A	8.3ms, half sine
Maximum Instantaneous Forward Voltage	V_F	1.3V	$I_{FM} = 1.0\text{A};$ $T_A = 25^\circ\text{C}^*$
Maximum DC Reverse Current At Rated DC Blocking Voltage	I_R	5.0 μA 500 μA	$T_J = 25^\circ\text{C}$ $T_J = 175^\circ\text{C}$
Maximum Reverse Recovery Time 1N4942-4944 1N4946-4947 1N4948	T_{rr}	150ns 250ns 500ns	$I_F = 0.5\text{A},$ $I_R = 1.0\text{A},$ $I_{rr} = 0.25\text{A}$
Typical Junction Capacitance	C_J	15pF	Measured at 1.0MHz, $V_R = 4.0\text{V}$

*Pulse test: Pulse width 300 μsec , Duty cycle 2%

1 Amp Fast Recovery Rectifier 200 to 1000 Volts

DO-41

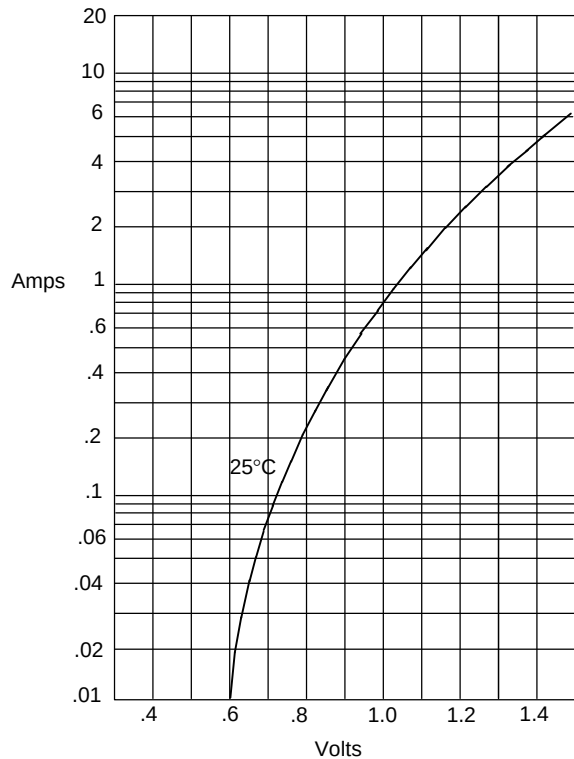


DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.166	.205	4.10	5.20	
B	.080	.107	2.00	2.70	
C	.028	.034	.70	.90	
D	1.000	---	25.40	---	

1N4942 thru 1N4948

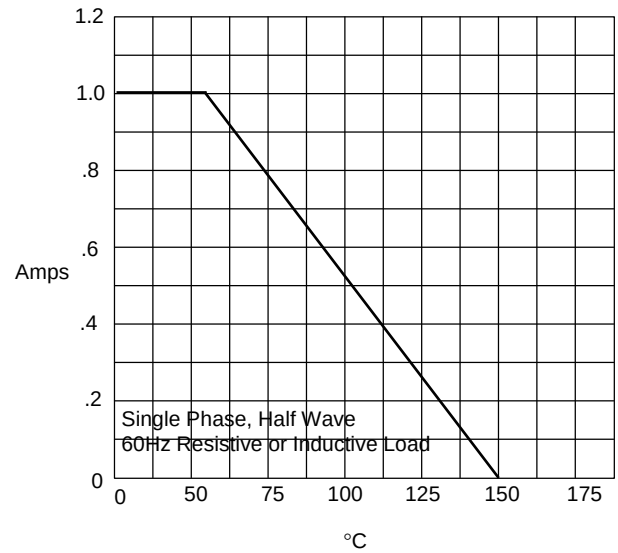


Figure 1
Typical Forward Characteristics



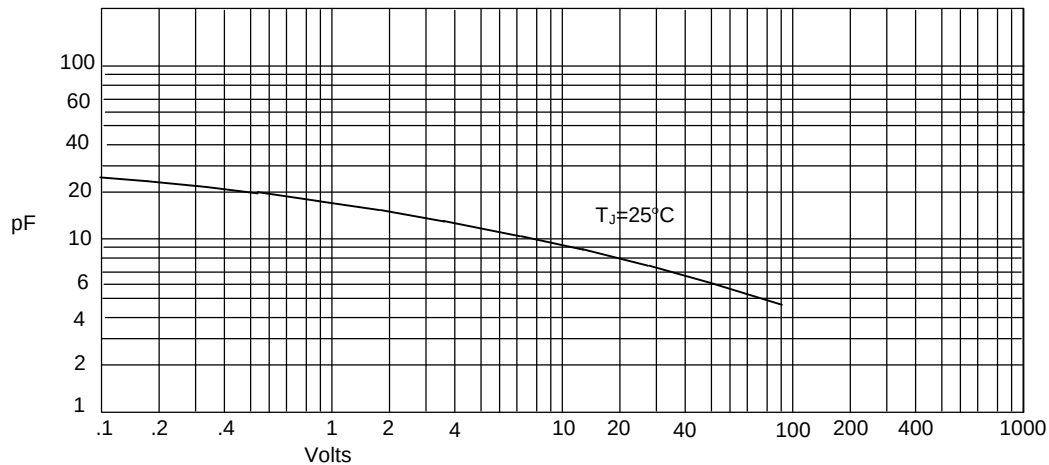
Instantaneous Forward Current - Amperes versus
Instantaneous Forward Voltage - Volts

Figure 2
Forward Derating Curve



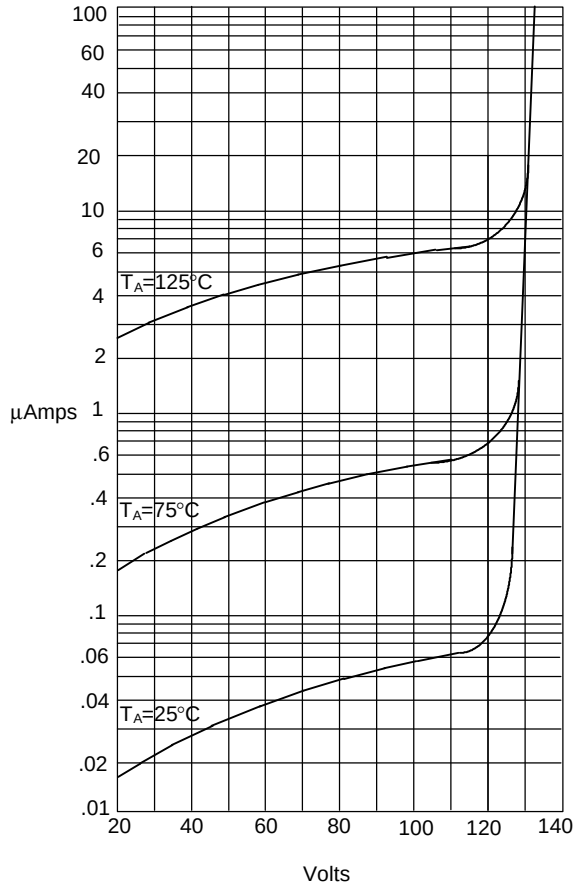
Average Forward Rectified Current - Amperes versus
Ambient Temperature - °C

Figure 3
Junction Capacitance



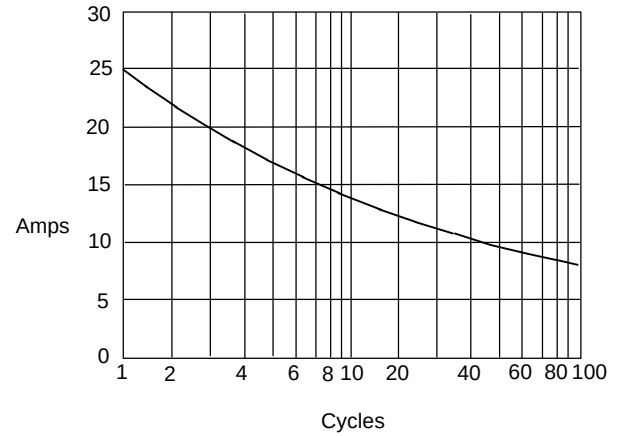
Junction Capacitance - pF versus
Reverse Voltage - Volts

Figure 4
Typical Reverse Characteristics



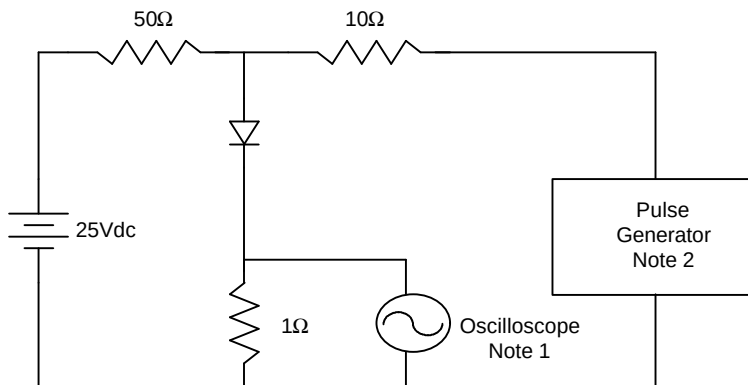
Instantaneous Reverse Leakage Current - MicroAmpere *versus*
Percent Of Rated Peak Reverse Voltage - Volts

Figure 5
Non-Repetitive Peak Forward Surge Current

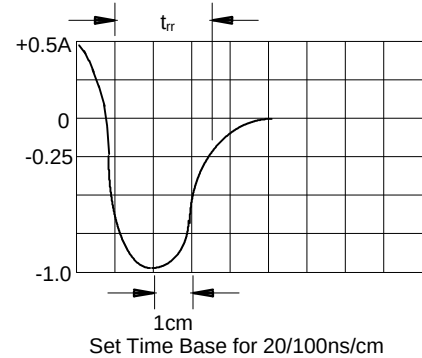


Peak Forward Surge Current - Amperes *versus*
Number Of Cycles At 60Hz - Cycles

Figure 6
Reverse Recovery Time Characteristic And Test Circuit Diagram



- Notes:
1. Rise Time = 7ns max.
Input impedance = 1 megohm, 22pF
 2. Rise Time = 10ns max.
Source impedance = 50 ohms
 3. Resistors are non-inductive



Set Time Base for 20/100ns/cm